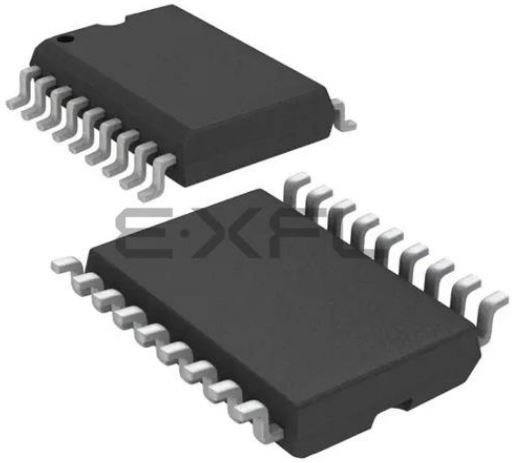

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What is "Embedded - Microcontrollers"?

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	Z8
Core Size	8-Bit
Speed	12MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	14
Program Memory Size	1KB (1K x 8)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	125 x 8
Voltage - Supply (Vcc/Vdd)	4.5V ~ 5.5V
Data Converters	-
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	18-SOIC (0.295", 7.50mm Width)
Supplier Device Package	-
Purchase URL	https://www.e-xfl.com/product-detail/zilog/z86e0412sec00tr

FEATURES

- 14 Input/Output Lines
- Six Vectored, Prioritized Interrupts (3 falling edge, 1 rising edge, 2 timers)
- Two Analog Comparators
- Program Options:
  - Low Noise
  - ROM Protect
  - Auto Latch
  - Watch-Dog Timer (WDT)
  - EPROM/Test Mode Disable
- Two Programmable 8-Bit Counter/Timers, Each with 6-Bit Programmable Prescaler
- WDT/ Power-On Reset (POR)
- On-Chip Oscillator that Accepts XTAL, Ceramic Resonance, LC, RC, or External Clock
- Clock-Free WDT Reset
- Low-Power Consumption (50 mw typical)
- Fast Instruction Pointer (1µs @ 12 MHz)
- RAM Bytes (125)

GENERAL DESCRIPTION

Zilog's Z86E04/E08 Microcontrollers (MCU) are One-Time Programmable (OTP) members of Zilog's single-chip Z8® MCU family that allow easy software development, debug, prototyping, and small production runs not economically desirable with masked ROM versions.

For applications demanding powerful I/O capabilities, the Z86E04/E08's dedicated input and output lines are grouped into three ports, and are configurable under software control to provide timing, status signals, or parallel I/O.

Two on-chip counter/timers, with a large number of user selectable modes, offload the system of administering real-time tasks such as counting/timing and I/O data communications.

Note: All Signals with an overline, "‾", are active Low, for example: B/$\overline{W}$ (WORD is active Low); $\overline{B}$/W (BYTE is active Low, only).

Power connections follow conventional descriptions below:

Connection	Circuit	Device
Power	V_{CC}	V_{DD}
Ground	GND	V_{SS}

PIN DESCRIPTION

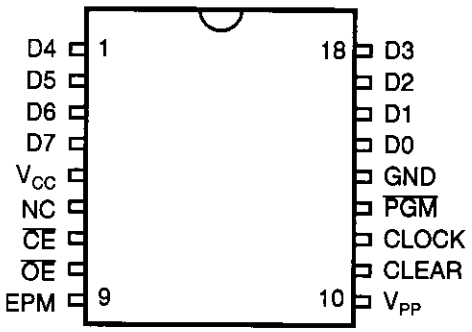


Figure 3. 18-Pin EPROM Mode Configuration

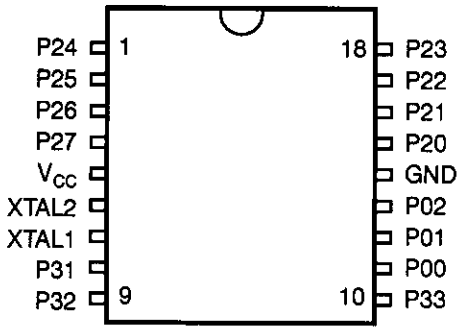


Figure 4. 18-Pin DIP/SOIC Mode Configuration

Table 1. 18-Pin DIP Pin Identification

EPROM Programming Mode			
Pin #	**Symbol**	**Function**	**Direction**
1–4	D4–D7	Data 4, 5, 6, 7	In/Output
5	V_{CC}	Power Supply	
6	NC	No Connection	
7	$\overline{CE}$	Chip Enable	Input
8	$\overline{OE}$	Output Enable	Input
9	EPM	EPROM Prog Mode	Input
10	V_{PP}	Prog Voltage	Input
11	Clear	Clear Clock	Input
12	Clock	Address	Input
13	$\overline{PGM}$	Prog Mode	Input
14	GND	Ground	
15–18	D0–D3	Data 0,1, 2, 3	In/Output

Table 2. 18-Pin DIP/SOIC Pin Identification

Standard Mode			
Pin #	**Symbol**	**Function**	**Direction**
1–4	P24–P27	Port 2, Pins 4,5,6,7	In/Output
5	V_{CC}	Power Supply	
6	XTAL2	Crystal Osc. Clock	Output
7	XTAL1	Crystal Osc. Clock	Input
8	P31	Port 3, Pin 1, AN1	Input
9	P32	Port 3, Pin 2, AN2	Input
10	P33	Port 3, Pin 3, REF	Input
11–13	P00–P02	Port 0, Pins 0,1,2	In/Output
14	GND	Ground	
15–18	P20–P23	Port 2, Pins 0,1,2,3	In/Output

ABSOLUTE MAXIMUM RATINGS

Stresses greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at any condition above those indicated in the operational sections of these specifications is not implied. Exposure to absolute maximum rating conditions for an extended period may affect device reliability. Total power dissipation should not exceed 462 mW for the package. Power dissipation is calculated as follows:

Total Power Dissipation = V_{DD} x [I_{DD}–(sum of I_{OH})]
+ sum of [(V_{DD}–V_{OH}) x I_{OH}]
+ sum of (V_{OL} x I_{OL})

Parameter	Min	Max	Units	Note
Ambient Temperature under Bias	–40	+105	C	
Storage Temperature	–65	+150	C	
Voltage on any Pin with Respect to V_{SS}	–0.7	+12	V	1
Voltage on V_{DD} Pin with Respect to V_{SS}	–0.3	+7	V	
Voltage on Pins 7, 8, 9, 10 with Respect to V_{SS}	–0.6	V_{DD}+1	V	2
Total Power Dissipation		1.65	W	
Maximum Allowable Current out of V_{SS}		300	mA	
Maximum Allowable Current into V_{DD}		220	mA	
Maximum Allowable Current into an Input Pin	–600	+600	µA	3
Maximum Allowable Current into an Open-Drain Pin	–600	+600	µA	4
Maximum Allowable Output Current Sinked by Any I/O Pin		25	mA	
Maximum Allowable Output Current Sourced by Any I/O Pin		25	mA	
Total Maximum Output Current Sinked by a Port		60	mA	
Total Maximum Output Current Sourced by a Port		45	mA	

Notes:

1. This applies to all pins except where otherwise noted. Maximum current into pin must be ± 600 µA.
2. There is no input protection diode from pin to V_{DD} (not applicable to EPROM Mode).
3. This excludes Pin 6 and Pin 7.
4. Device pin is not at an output Low state.

STANDARD TEST CONDITIONS

The characteristics listed below apply for standard test conditions as noted. All voltages are referenced to Ground. Positive current flows into the referenced pin (Figure 5).

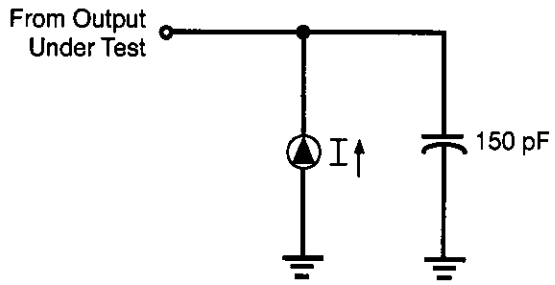


Figure 5. Test Load Diagram

CAPACITANCE

T_A = 25°C, V_{CC} = GND = 0V, f = 1.0 MHz, unmeasured pins returned to GND.

Parameter	Min	Max
Input capacitance	0	10 pF
Output capacitance	0	20 pF
I/O capacitance	0	25 pF

DC ELECTRICAL CHARACTERISTICS

Standard Temperature

Sym	Parameter	V_{CC} [4]	T_A = 0°C to +70°C Min	Max	Typical @ 25°C	Units	Conditions	Notes
V_{INMAX}	Max Input Voltage	4.5V		12		V	I_{In}<250 µA	1
		5.5V		12		V	I_{In}<250 µA	1
V_{CH}	Clock Input High Voltage	4.5V	0.8 V_{CC}	V_{CC}+0.3	2.8	V	Driven by External Clock Generator	
		5.5V	0.8 V_{CC}	V_{CC}+0.3	2.8	V	Driven by External Clock Generator	
V_{CL}	Clock Input Low Voltage	4.5V	V_{SS}–0.3	0.2 V_{CC}	1.7	V	Driven by External Clock Generator	
		5.5V	V_{SS}–0.3	0.2 V_{CC}	1.7	V	Driven by External Clock Generator	
V_{IH}	Input High Voltage	4.5V	0.7 V_{CC}	V_{CC}+0.3	2.8	V		
		5.5V	0.7 V_{CC}	V_{CC}+0.3	2.8	V		
V_{IL}	Input Low Voltage	4.5V	V_{SS}–0.3	0.2 V_{CC}	1.5	V		
		5.5V	V_{SS}–0.3	0.2 V_{CC}	1.5	V		
V_{OH}	Output High Voltage	4.5V	V_{CC}–0.4		4.8	V	I_{OH} = –2.0 mA	5
		5.5V	V_{CC}–0.4		4.8	V	I_{OH} = –2.0 mA	5
		4.5V	V_{CC}–0.4		4.8	V	Low Noise @ I_{OH} = –0.5 mA	
		5.5V	V_{CC}–0.4		4.8	V	Low Noise @ I_{OH} = –0.5 mA	
V_{OL1}	Output Low Voltage	4.5V		0.8	0.1	V	I_{OL} = +4.0 mA	5
		5.5V		0.4	0.1	V	I_{OL} = +4.0 mA	5
		4.5V		0.4	0.1	V	Low Noise @ I_{OL} = 1.0 mA	
		5.5V		0.4	0.1	V	Low Noise @ I_{OL} = 1.0 mA	
V_{OL2}	Output Low Voltage	4.5V		0.8	0.8	V	I_{OL} = +12 mA,	5
		5.5V		0.8	0.8	V	I_{OL} = +12 mA,	5
V_{OFFSET}	Comparator Input Offset Voltage	4.5V		25.0	10.0	mV		
		5.5V		25.0	10.0	mV		
V_{LV}	V_{CC} Low Voltage Auto Reset		2.2	3.0	2.8	V	@ 6 MHz Max. Int. CLK Freq.	
I_{IL}	Input Leakage (Input Bias Current of Comparator)	4.5V	–1.0	1.0		µA	V_{IN} = 0V, V_{CC}	
		5.5V	–1.0	1.0		µA	V_{IN} = 0V, V_{CC}	
I_{OL}	Output Leakage	4.5V	–1.0	1.0		µA	V_{IN} = 0V, V_{CC}	
		5.5V	–1.0	1.0		µA	V_{IN} = 0V, V_{CC}	
V_{ICR}	Comparator Input Common Mode Voltage Range		0	V_{CC}–1.0		V		

DC ELECTRICAL CHARACTERISTICS

Extended Temperature

Sym	Parameter	V_{CC} [4]	T_A = –40°C to +105°C Min	Max	Typical @ 25°C	Units	Conditions	Notes
V_{INMAX}	Max Input Voltage	4.5V		12.0		V	I_{IN} < 250 µA	1
		5.5V		12.0		V	I_{IN} < 250 µA	1
V_{CH}	Clock Input High Voltage	4.5V	0.8 V_{CC}	V_{CC}+0.3	2.8	V	Driven by External Clock Generator	
		5.5V	0.8 V_{CC}	V_{CC}+0.3	2.8	V	Driven by External Clock Generator	
V_{CL}	Clock Input Low Voltage	4.5V	V_{SS}–0.3	0.2 V_{CC}	1.7	V	Driven by External Clock Generator	
		5.5V	V_{SS}–0.3	0.2 V_{CC}	1.7	V	Driven by External Clock Generator	
V_{IH}	Input High Voltage	4.5V	0.7 V_{CC}	V_{CC}+0.3	2.8	V		
		5.5V	0.7 V_{CC}	V_{CC}+0.3	2.8	V		
V_{IL}	Input Low Voltage	4.5V	V_{SS}–0.3	0.2 V_{CC}	1.5	V		
		5.5V	V_{SS}–0.3	0.2 V_{CC}	1.5	V		
V_{OH}	Output High Voltage	4.5V	V_{CC}–0.4		4.8	V	I_{OH} = –2.0 mA	5
		5.5V	V_{CC}–0.4		4.8	V	I_{OH} = –2.0 mA	5
		4.5V	V_{CC}–0.4			V	Low Noise @ I_{OH} = –0.5 mA	
		5.5V	V_{CC}–0.4			V	Low Noise @ I_{OH} = –0.5 mA	
V_{OL1}	Output Low Voltage	4.5V		0.4	0.1	V	I_{OL} = +4.0 mA	5
		5.5V		0.4	0.1	V	I_{OL} = +4.0 mA	5
		4.5V		0.4	0.1	V	Low Noise @ I_{OL} = 1.0 mA	
		5.5V		0.4	0.1	V	Low Noise @ I_{OL} = 1.0 mA	
V_{OL2}	Output Low Voltage	4.5V		1.0	0.3	V	I_{OL} = +12 mA,	5
		5.5V		1.0	0.3	V	I_{OL} = +12 mA,	5
V_{OFFSET}	Comparator Input Offset Voltage	4.5V		25.0	10.0	mV		
		5.5V		25.0	10.0	mV		
V_{LV}	V_{CC} Low Voltage Auto Reset		1.8	3.8	2.8	V	@ 6 MHz Max. Int. CLK Freq.	3
I_{IL}	Input Leakage (Input Bias Current of Comparator)	4.5V		–1.0	1.0	µA	V_{IN} = 0V, V_{CC}	
		5.5V		–1.0	1.0	µA	V_{IN} = 0V, V_{CC}	
I_{OL}	Output Leakage	4.5V		–1.0	1.0	µA	V_{IN} = 0V, V_{CC}	
		5.5V		–1.0	1.0	µA	V_{IN} = 0V, V_{CC}	
V_{ICR}	Comparator Input Common Mode Voltage Range		0	V_{CC} –1.5		V		

DC ELECTRICAL CHARACTERISTICS (Continued)

Sym	Parameter	V_{CC} [4]	T_A = –40°C to +105°C Min	Max	Typical @ 25°C	Units	Conditions	Notes
I_{CC}	Supply Current	4.5V		11.0	6.8	mA	All Output and I/O Pins Floating @ 2 MHz	5,7
		5.5V		11.0	6.8	mA	All Output and I/O Pins Floating @ 2 MHz	5,7
		4.5V		15.0	8.2	mA	All Output and I/O Pins Floating @ 8 MHz	5,7
		5.5V		15.0	8.2	mA	All Output and I/O Pins Floating @ 8 MHz	5,7
		4.5V		20.0	12.0	mA	All Output and I/O Pins Floating @ 12 MHz	5,7
		5.5V		20.0	12.0	mA	All Output and I/O Pins Floating @ 12 MHz	5,7
I_{CC1}	Standby Current	4.5V		5.0	2.5	mA	HALT Mode V_{IN} = 0V, V_{CC} @ 2 MHz	5,7
		5.5V		5.0	2.5	mA	HALT Mode V_{IN} = 0V, V_{CC} @ 2 MHz	5,7
		4.5V		5.0	3.0	mA	HALT Mode V_{IN} = 0V, V_{CC} @ 8 MHz	5,7
		5.5V		5.0	3.0	mA	HALT Mode V_{IN} = 0V, V_{CC} @ 8 MHz	5,7
		4.5V		7.0	4.0	mA	HALT Mode V_{IN} = 0V, V_{CC} @ 12 MHz	5,7
		5.5V		7.0	4.0	mA	HALT Mode V_{IN} = 0V, V_{CC} @ 12 MHz	5,7
I_{CC}	Supply Current (Low Noise Mode)	4.5V		11.0	6.8	mA	All Output and I/O Pins Floating @ 1 MHz	7
		5.5V		11.0	6.8	mA	All Output and I/O Pins Floating @ 1 MHz	7
		4.5V		13.0	7.5	mA	All Output and I/O Pins Floating @ 2 MHz	7
		5.5V		13.0	7.5	mA	All Output and I/O Pins Floating @ 2 MHz	7
		4.5V		15.0	8.2	mA	All Output and I/O Pins Floating @ 4 MHz	7
		5.5V		15.0	8.2	mA	All Output and I/O Pins Floating @ 4 MHz	7

Sym	Parameter	V_{CC} [4]	T_A = –40°C to +105°C Min	Max	Typical @ 25°C	Units	Conditions	Notes
I_{CC1}	Standby Current (Low Noise Mode)	4.5V		4.0	2.5	mA	HALT Mode V_{IN} = 0V, V_{CC} @ 1 MHz	7
		5.5V		4.0	2.5	mA	HALT Mode V_{IN} = 0V, V_{CC} @ 1 MHz	7
		4.5V		4.5	2.8	mA	HALT Mode V_{IN} = 0V, V_{CC} @ 2 MHz	7
		5.5V		4.5	2.8	mA	HALT Mode V_{IN} = 0V, V_{CC} @ 2 MHz	7
		4.5V		5.0	3.0	mA	HALT Mode V_{IN} = 0V, V_{CC} @ 4 MHz	7
		5.5V		5.0	3.0	mA	HALT Mode V_{IN} = 0V, V_{CC} @ 4 MHz	7
I_{CC2}	Standby Current	4.5V		20	1.0	µA	STOP Mode V_{IN} = 0V, V_{CC} WDT is not Running	7,8
		5.5V		20	1.0	µA	STOP Mode V_{IN} = 0V, V_{CC} WDT is not Running	7,8
I_{ALL}	Auto Latch Low Current	4.5V		40	16	µA	$0V < V_{IN} < V_{CC}$	
		5.5V		40	16	µA	$0V < V_{IN} < V_{CC}$	
I_{ALH}	Auto Latch High Current	4.5V		–20.0	–8.0	µA	$0V < V_{IN} < V_{CC}$	
		5.5V		–20.0	–8.0	µA	$0V < V_{IN} < V_{CC}$	

Notes:

1. Port 2 and Port 0 only
2. V_{SS} = 0V = GND
3. The device operates down to V_{LV} of the specified frequency for V_{LV}. The minimum operational V_{CC} is determined on the value of the voltage V_{LV} at the ambient temperature. The V_{LV} increases as the temperature decreases.
4. V_{CC} = 4.5V to 5.5V, typical values measured at V_{CC} = 5.0V
5. Standard Mode (not Low EMI Mode)
6. Z86E08 only
7. All outputs unloaded and all inputs are at V_{CC} or V_{SS} level.
8. If analog comparator is selected, then the comparator inputs must be at V_{CC} level.

AC ELECTRICAL CHARACTERISTICS

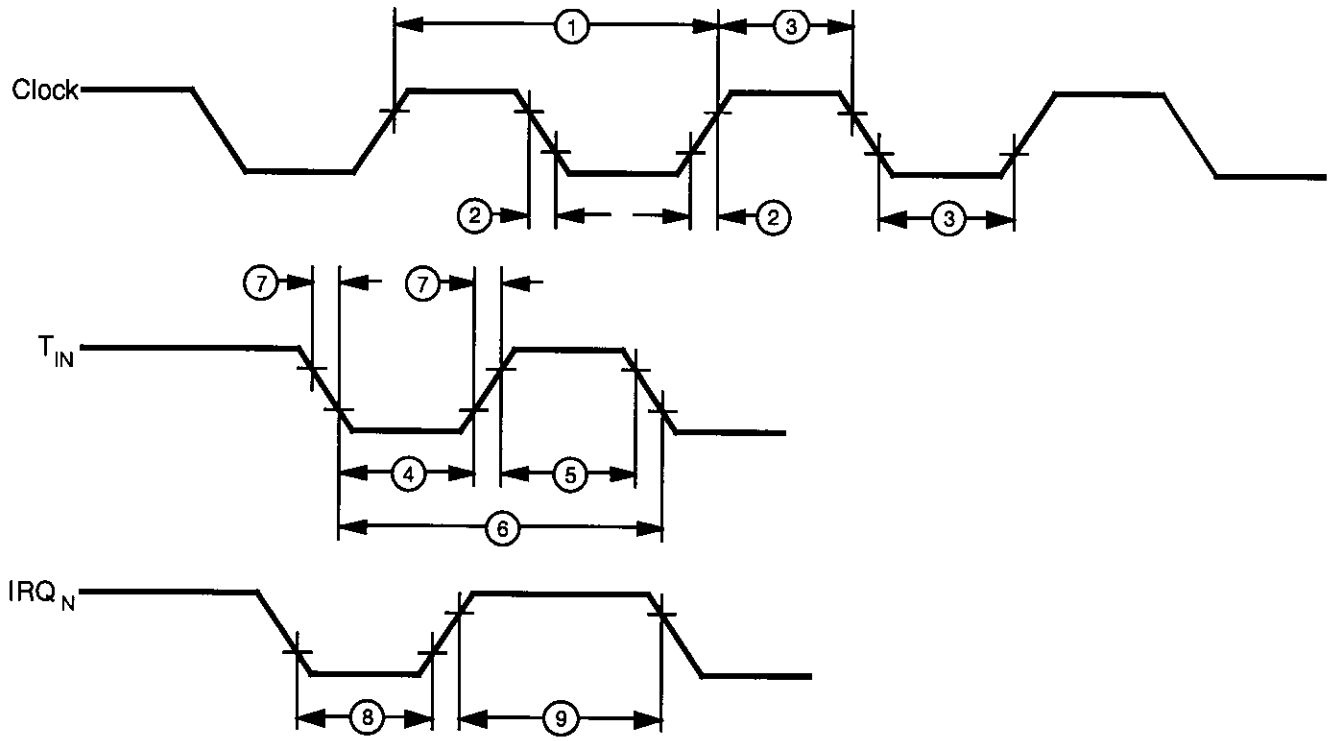


Figure 6. AC Electrical Timing Diagram

AC ELECTRICAL CHARACTERISTICS

Timing Table (Standard Mode for SCLK/TCLK = XTAL/2)
Standard Temperature

15				T_A= 0 °C to +70 °C						
				8 MHz		12 MHz				
No	Symbol	Parameter	V_{CC}	Min	Max	Min	Max	Units	Notes
1	TpC	Input Clock Period	4.5V	125	DC	83	DC	ns	1
			5.5V	125	DC	83	DC	ns	1
2	TrC,TfC	Clock Input Rise and Fall Times	4.5V		25		15	ns	1
			5.5V		25		15	ns	1
3	TwC	Input Clock Width	4.5V	62		41		ns	1
			5.5V	62		41		ns	1
4	TwTinL	Timer Input Low Width	4.5V	100		100		ns	1
			5.5V	70		70		ns	1
5	TwTinH	Timer Input High Width	4.5V	5TpC		5TpC			1
			5.5V	5TpC		5TpC			1
6	TpTin	Timer Input Period	4.5V		8TpC	8TpC			1
			5.5V		8TpC	8TpC			1
7	TrTin, TtTin	Timer Input Rise and Fall Time	4.5V		100		100	ns	1
			5.5V		100		100	ns	1
8	TwIL	Int. Request Input Low Time	4.5V	70		70		ns	1,2
			5.5V	70		70		ns	1,2
9	TwIH	Int. Request Input High Time	4.5V		5TpC	5TpC			1,2
			5.5V		5TpC	5TpC			1,2
10	Twdt	Watch-Dog Timer Delay Time for Timeout	4.5V	12		12		ms	1
			5.5V	12		12		ms	1
11	Tpor	Power-On Reset Time	4.5V	20	80	20	80	ms	1
			5.5V	20	80	20	80	ms	1

Notes:

1. Timing Reference uses 0.7 V_{CC} for a logic 1 and 0.2 V_{CC} for a logic 0.
2. Interrupt request through Port 3 (P33–P31).

LOW NOISE VERSION

Low EMI Emission

The Z86E04/E08 can be programmed to operate in a Low EMI Emission Mode by means of a mask ROM bit option. Use of this feature results in:

- All pre-driver slew rates reduced to 10 ns typical.
- Internal SCLK/TCLK operation limited to a maximum of 4 MHz–250 ns cycle time.
- Output drivers have resistances of 500 Ohms (typical).
- Oscillator divide-by-two circuitry eliminated.

The Low EMI Mode is mask-programmable to be selected by the customer at the time the ROM code is submitted.

PIN FUNCTIONS

OTP Programming Mode

D7–D0 *Data Bus.* Data can be read from, or written to, the EPROM through this data bus.

V_{CC} *Power Supply.* It is typically 5V during EPROM Read Mode and 6.4V during the other modes (Program, Program Verify, and so on).

$\overline{CE}$ *Chip Enable* (active Low). This pin is active during EPROM Read Mode, Program Mode, and Program Verify Mode.

$\overline{OE}$ *Output Enable* (active Low). This pin drives the Data Bus direction. When this pin is Low, the Data Bus is output. When High, the Data Bus is input.

EPM *EPROM Program Mode.* This pin controls the different EPROM Program Modes by applying different voltages.

V_{PP} *Program Voltage.* This pin supplies the program voltage.

Clear *Clear* (active High). This pin resets the internal address counter at the High Level.

Clock *Address Clock.* This pin is a clock input. The internal address counter increases by one with one clock cycle.

$\overline{PGM}$ *Program Mode* (active Low). A Low level at this pin programs the data to the EPROM through the Data Bus.

Application Precaution

The production test-mode environment may be enabled accidentally during normal operation if ***excessive noise*** surges above V_{CC} occur on the XTAL1 pin.

In addition, processor operation of Z8 OTP devices may be affected by ***excessive noise*** surges on the V_{PP}, $\overline{CE}$, EPM, $\overline{OE}$ pins while the microcontroller is in Standard Mode.

Recommendations for dampening voltage surges in both test and OTP Mode include the following:

- Using a clamping diode to V_{CC}.
- Adding a capacitor to the affected pin.

Note: Programming the EPROM/Test Mode Disable option will prevent accidental entry into EPROM Mode or Test Mode.

PIN FUNCTIONS (Continued)

XTAL1, XTAL2 *Crystal In, Crystal Out* (time-based input and output, respectively). These pins connect a parallel-resonant crystal, LC, or an external single-phase clock (8 MHz or 12 MHz max) to the on-chip clock oscillator and buffer.

Port 0, P02–P00. Port 0 is a 3-bit bidirectional, Schmitt-triggered CMOS-compatible I/O port. These three I/O lines can be globally configured under software control to be inputs or outputs (Figure 7).

Auto Latch. The Auto Latch puts valid CMOS levels on all CMOS inputs (except P33, P32, P31) that are not externally driven. A valid CMOS level, rather than a floating node, reduces excessive supply current flow in the input buffer. On Power-up and Reset, the Auto Latch will set the ports to an undetermined state of 0 or 1. Default condition is Auto Latches enabled.

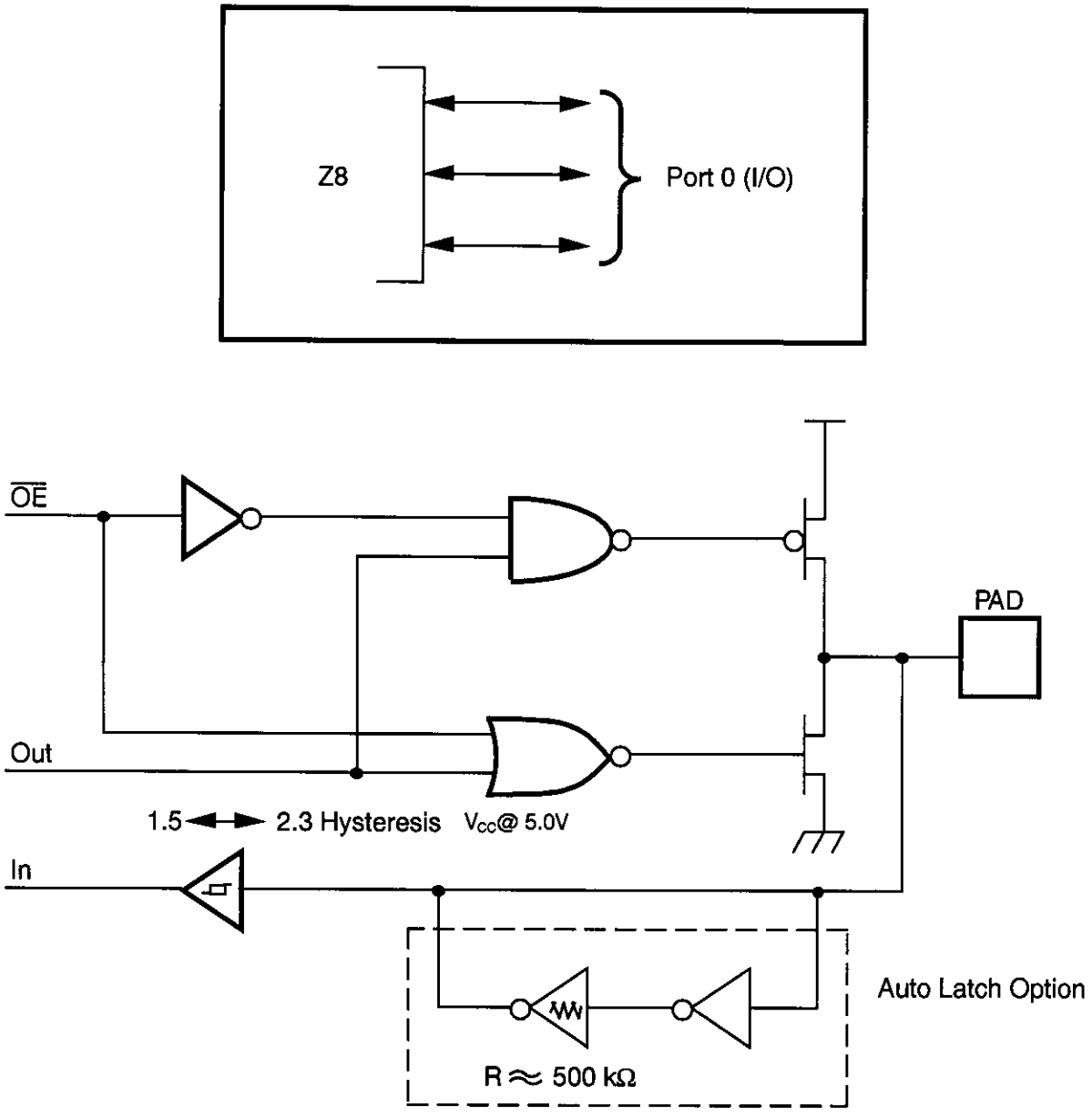


Figure 7. Port 0 Configuration

Comparator Inputs. Two analog comparators are added to input of Port 3, P31, and P32, for interface flexibility. The comparators reference voltage P33 (REF) is common to both comparators.

Typical applications for the on-board comparators; Zero crossing detection, A/D conversion, voltage scaling, and threshold detection. In Analog Mode, P33 input functions serve as a reference voltage to the comparators.

The dual comparator (common inverting terminal) features a single power supply which discontinues power in STOP Mode. The common voltage range is 0–4 V when the V_{CC} is 5.0V; the power supply and common mode rejection ratios are 90 dB and 60 dB, respectively.

Interrupts are generated on either edge of Comparator 2's output, or on the falling edge of Comparator 1's output. The comparator output is used for interrupt generation, Port 3 data inputs, or T_{IN} through P31. Alternatively, the comparators can be disabled, freeing the reference input (P33) for use as IRQ1 and/or P33 input.

FUNCTIONAL DESCRIPTION

The following special functions have been incorporated into the Z8 devices to enhance the standard Z8 core architecture to provide the user with increased design flexibility.

RESET. This function is accomplished by means of a Power-On Reset or a Watch-Dog Timer Reset. Upon power-up, the Power-On Reset circuit waits for T_{POR} ms, plus 18 clock cycles, then starts program execution at address 000C (Hex) (Figure 10). The Z8 control registers' reset value is shown in Table 3.

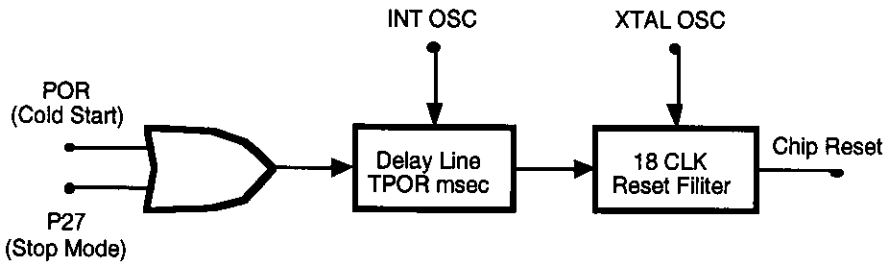


Figure 10. Internal Reset Configuration

Power-On Reset (POR). A timer circuit clocked by a dedicated on-board RC oscillator is used for a POR timer function. The POR time allows V_{CC} and the oscillator circuit to stabilize before instruction execution begins. The POR timer circuit is a one-shot timer triggered by one of the four following conditions:

- Power-bad to power-good status
- Stop-Mode Recovery
- WDT time-out
- WDH time-out

Watch-Dog Timer Reset. The WDT is a retriggerable one-shot timer that resets the Z8 if it reaches its terminal count. The WDT is initially enabled by executing the WDT instruction and is retriggered on subsequent execution of the WDT instruction. The timer circuit is driven by an on-board RC oscillator.

Program Memory. The Z86E04/E08 addresses up to 1K/2KB of Internal Program Memory (Figure 11). The first 12 bytes of program memory are reserved for the interrupt vectors. These locations contain six 16-bit vectors that correspond to the six available interrupts. Bytes 0–1024/2048 are on-chip one-time programmable ROM.

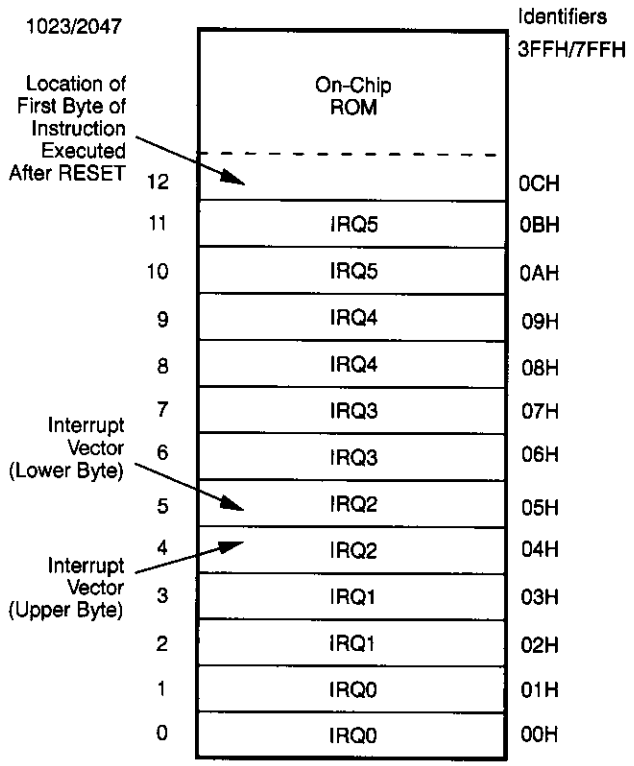


Figure 11. Program Memory Map

Register File. The Register File consists of three I/O port registers, 124 general-purpose registers, and 14 control and status registers R0–R3, R4–R127 and R241–R255, respectively (Figure 12). General-purpose registers occupy the 04H to 7FH address space. I/O ports are mapped as per the existing CMOS Z8.

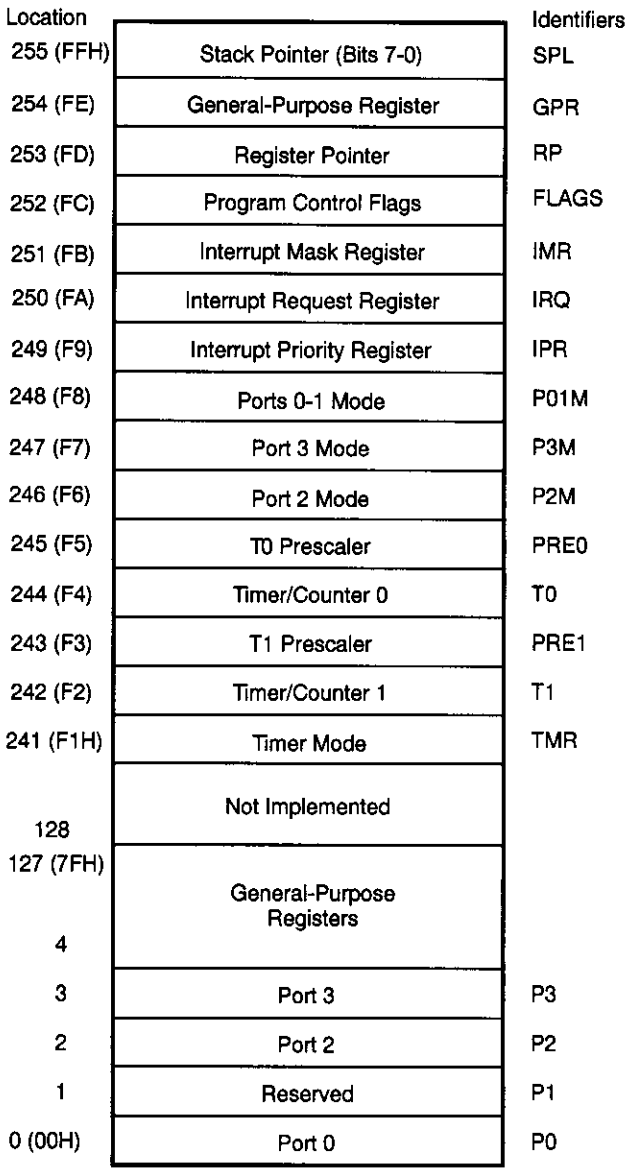


Figure 12. Register File

FUNCTIONAL DESCRIPTION (Continued)

Table 5. Typical Frequency vs. RC Values
V_{CC} = 5.0V @ 25°C

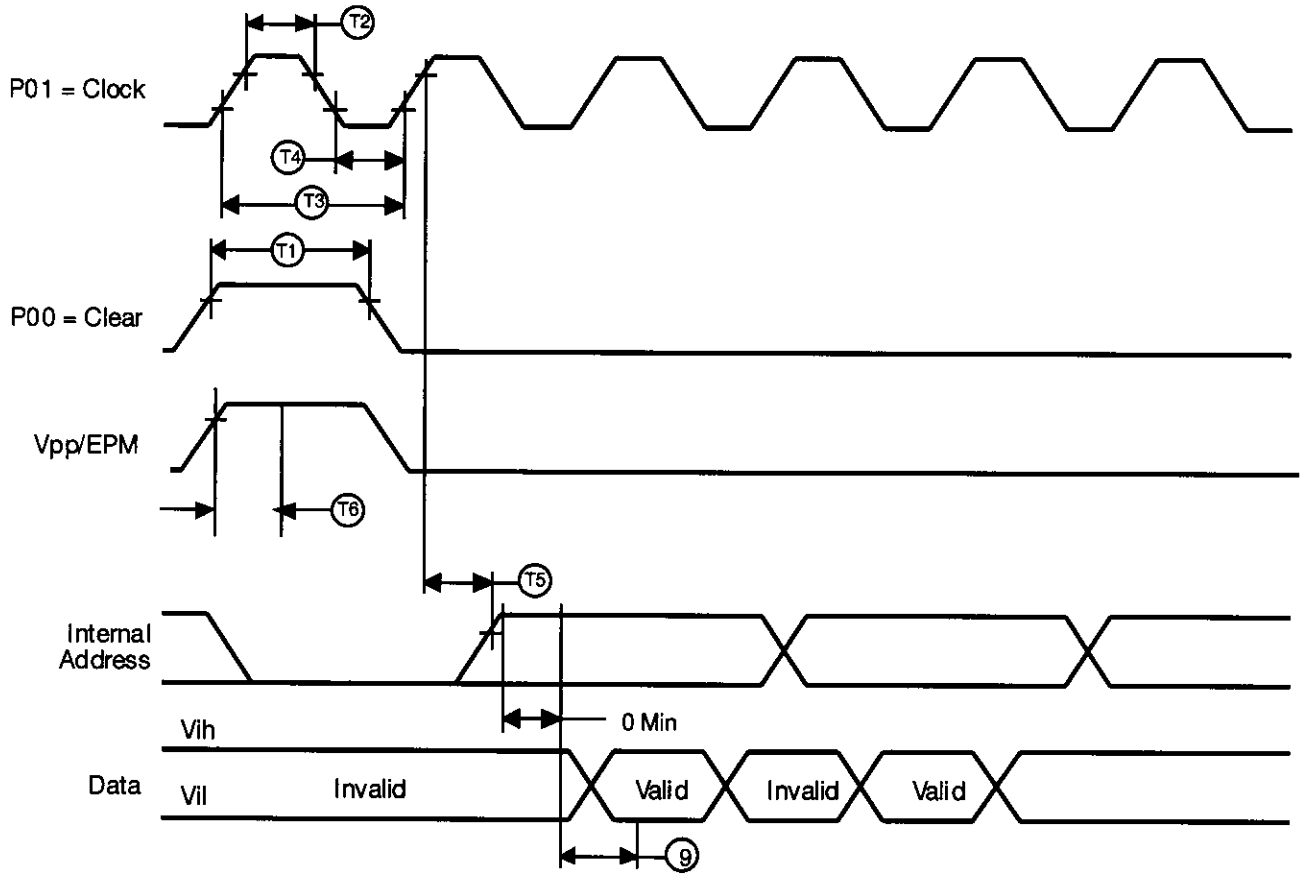
	Load Capacitor							
	33 pFd		56 pFd		100 pFd		0.00 1µFd	
Resistor (R)	A(Hz)	B(Hz)	A(Hz)	B(Hz)	A(Hz)	B(Hz)	A(Hz)	B(Hz)
1.0M	33K	31K	20K	20K	12K	11K	1.4K	1.4K
560K	56K	52K	34K	32K	20K	19K	2.5K	2.4K
220K	144K	130K	84K	78K	48K	45K	6K	6K
100K	315K	270K	182K	164K	100K	95K	12K	12K
56K	552K	480K	330K	300K	185K	170K	23K	22K
20K	1.4M	1M	884K	740K	500K	450K	65K	61K
10K	2.6M	2M	1.6M	1.3M	980K	820K	130K	123K
5K	4.4M	3M	2.8M	2M	1.7K	1.3M	245K	225K
2K	8M	5M	6M	4M	3.8K	2.7M	600K	536K
1K	12M	7M	8.8M	6M	6.3K	4.2M	1.0M	950K

Notes:
A = STD Mode Frequency.
B = Low EMI Mode Frequency.

Table 6. Typical Frequency vs. RC Values
V_{CC} = 3.3V @ 25°C

	Load Capacitor							
Resistor (R)	33 pFd		56 pFd		100 pFd		0.00 1µFd	
	A(Hz)	B(Hz)	A(Hz)	B(Hz)	A(Hz)	B(Hz)	A(Hz)	B(Hz)
1.0M	18K	18K	12K	12K	7.4K	7.7K	1K	1K
560K	30K	30K	20K	20K	12K	12K	1.6K	1.6K
220K	70K	70K	47K	47K	30K	30K	4K	4K
100K	150K	148K	97K	96K	60K	60K	8K	8K
56K	268K	250K	176K	170K	100K	100K	15K	15K
20K	690M	600K	463K	416K	286K	266K	40K	40K
10K	1.2M	1M	860K	730K	540K	480K	80K	76K
5K	2M	1.7M	1.5M	1.2M	950K	820K	151K	138K
2K	4.6M	3M	3.3M	2.4M	2.2M	1.6M	360K	316K
1K	7M	4.6M	5M	3.6M	3.6K	2.6M	660K	565K

Notes:
A = STD Mode Frequency.
B = Low EMI Mode Frequency.



Legend:	
T1 Reset Clock Width	30 ns Min
T2 Input Clock High	100 ns Min
T3 Input Clock Period	200 ns Min
T4 Input Clock Low	100 ns Min
T5 Clock to Address Counter Out Delay	15 ns Max
T6 Epm/Vpp Set up Time	40 µs Min

Figure 18. Z86E04/E08 Address Counter Waveform

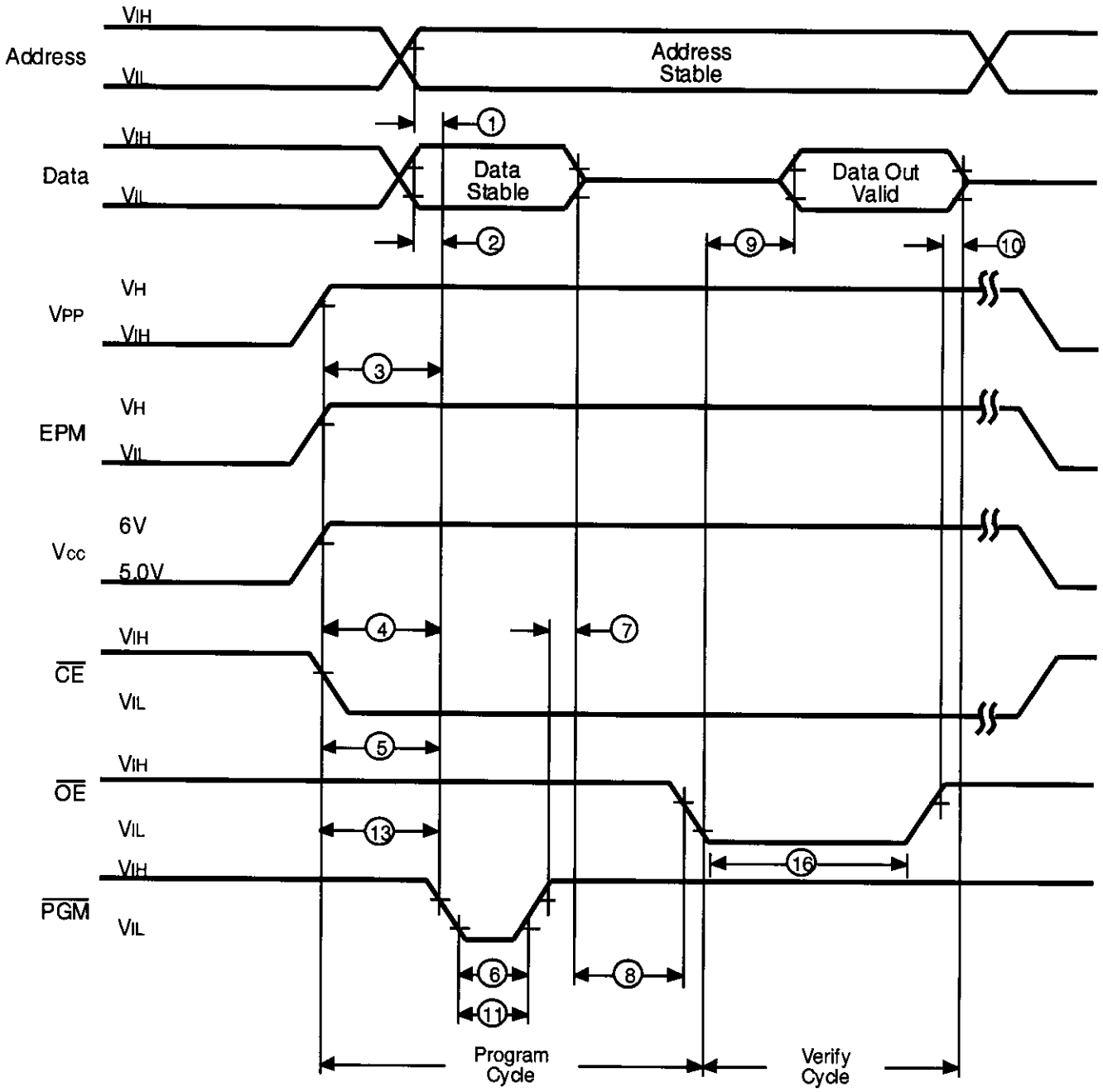


Figure 20. Z86E04/E08 Programming Waveform (Program and Verify)

FUNCTIONAL DESCRIPTION (Continued)

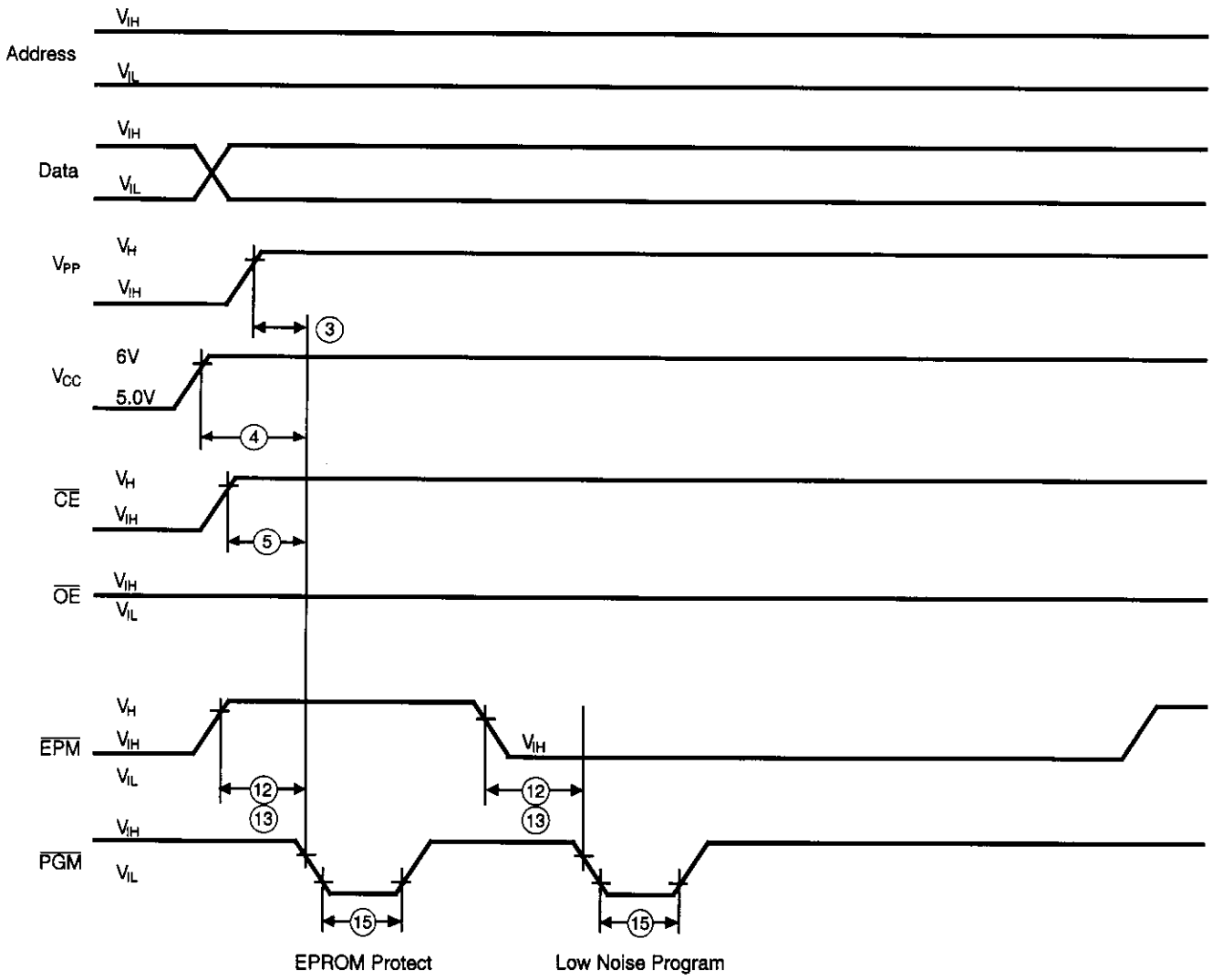


Figure 21. Z86E04/E08 Programming Options Waveform (EPROM Protect and Low Noise Program)

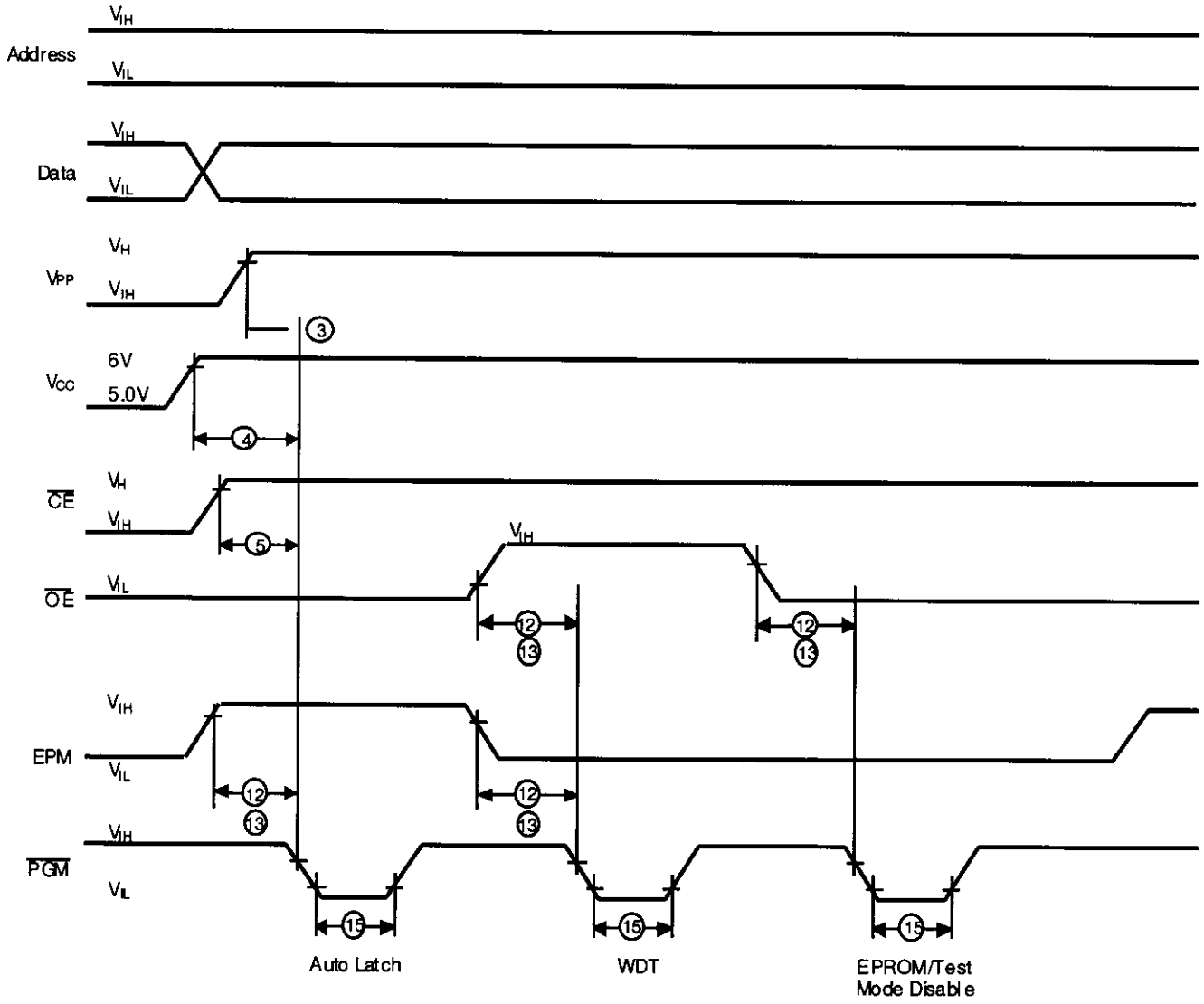


Figure 22. Z86E04/E08 Programming Options Waveform (Auto Latch Disable, Permanent WDT Enable and EPROM/Test Mode Disable)

Z8 CONTROL REGISTERS (Continued)

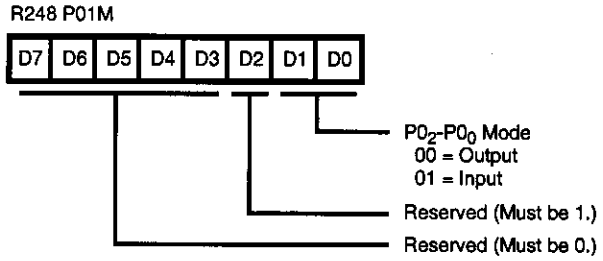


Figure 31. Port 0 and 1 Mode Register ($F8_H$: Write Only)

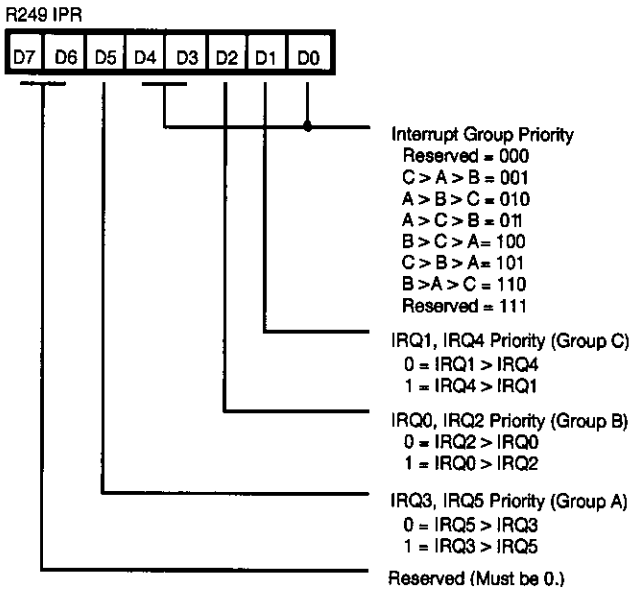


Figure 32. Interrupt Priority Register ($F9_H$: Write Only)

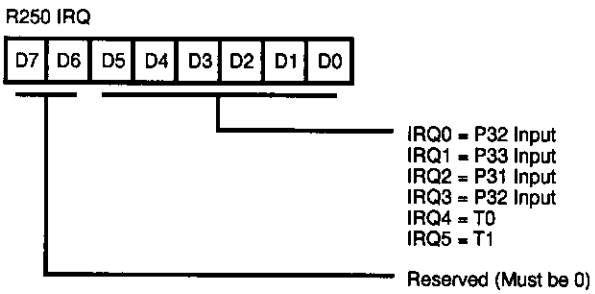


Figure 33. Interrupt Request Register (FA_H: Read/Write)

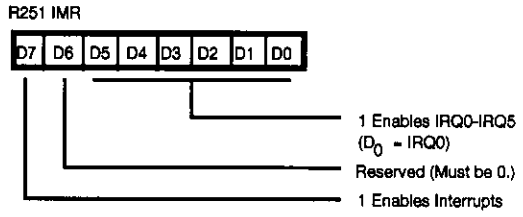


Figure 34. Interrupt Mask Register (FB_H: Read/Write)

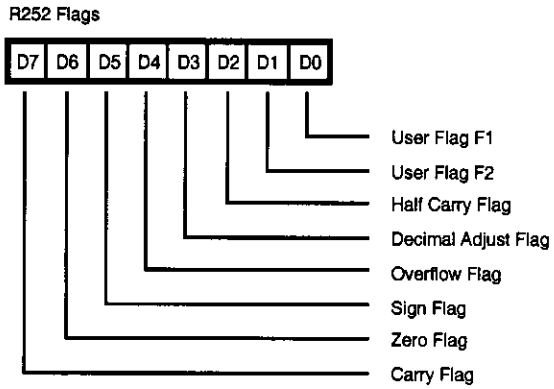


Figure 35. Flag Register (FC_H: Read/Write)

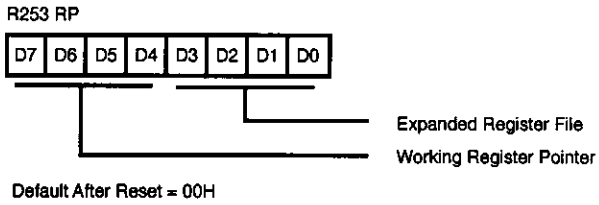


Figure 36. Register Pointer (FD_H: Read/Write)

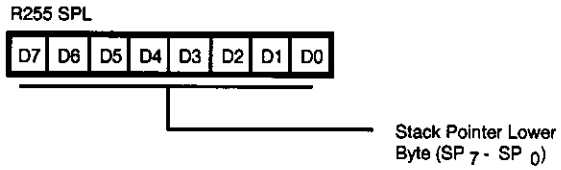


Figure 37. Stack Pointer (FF_H: Read/Write)